

# JAN2N1486

Request a Quote

### **JAN2N1486 Information**

Heisener.com	Part Number	JAN2N1486	
	Manufacturer	Microsemi Corporation	
	Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single	
	Description	TRANS NPN 55V 3A	
	Package	TO-233AA, TO-8-3 Lens Top Metal Can	
		For the pricing/inventory/lead time, please contact	
For Reference Only		us	
		Website: https://www.heisener.com	
		E-mail: salesdept@heisener.com	

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



# **JAN2N1486 Specifications**

Manufacturer Part Number	JAN2N1486
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-233AA, TO-8-3 Lens Top Metal Can
Series	Military, MIL-PRF-19500/207
Transistor Type	NPN
Current - Collector (Ic) (Max)	3A
Voltage - Collector Emitter Breakdown (Max)	55V
Vce Saturation (Max) @ Ib, Ic	750mV @ 40mA, 750mA
Current - Collector Cutoff (Max)	15µA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	35 @ 750mA, 4V
Power - Max	1.75W
Frequency - Transition	-
Operating Temperature	-65°C ~ 200°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-233AA, TO-8-3 Lens Top Metal Can
Supplier Device Package	TO-8
	Report errors?

#### **JAN2N1486 Guarantees**



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

#### Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about JAN2N1486, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com